SKKT 57, SKKH 57, SKKT 57B



SEMIPACK[®] 1

Thyristor / Diode Modules

SKKT 57
SKKH 57
SKKT 57B

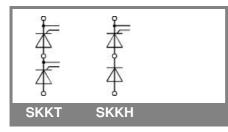
Features

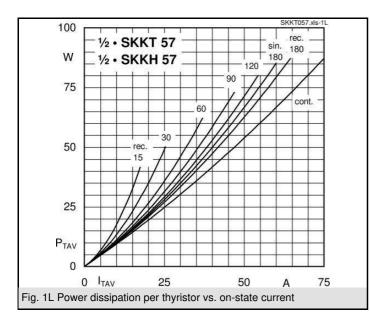
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered jounts for high reliability
- UL recognized, file no. E 63 532

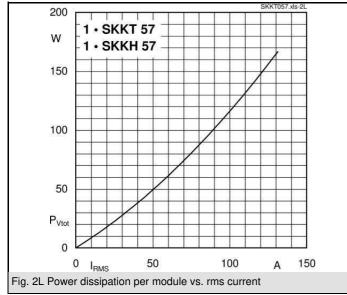
Typical Applications*

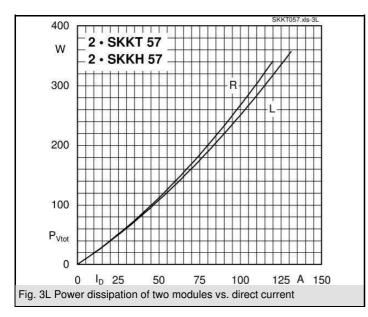
- DC motor control
 (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)
- 1) See the assembly instructions

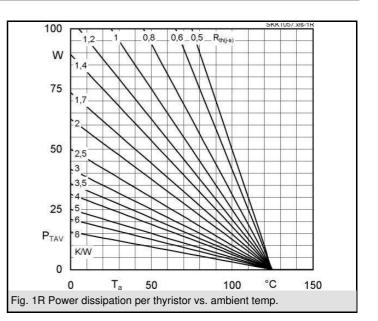
V _{RSM}	V _{RSM} V _{RRM} , V _{DRM} I _{TRMS} = 95 A (maximum value for continuous operation)						
					A (sin. 180; T _c = 80 °C)		
900	800						
1300 1200		SKKT 57/12E			SKKH 57/12E		
1500	1400	SKKT 57/14E	SKKT 57B14E		SKKH 57/14E		
1700	1600	SKKT 57/16E	SKKT 57B16E		SKKH 57/16E		
1900	1800	SKKT 57/18E	SKKT 57B18E		SKKH 57/18E		
Symbol	Conditions			Value	25	Units	
I _{TAV}	sin. 180; T _c = 85 (1	00) °C·		50 (35		A	
I _D	$P3/180; T_a = 45 °C$			57 / 68		A	
D	P3/180F; T _a = 35 °			100 /130		А	
I _{RMS}				130 / 3 x 100		А	
I _{TSM}	T _{vi} = 25 °C; 10 ms			1500		Α	
$T_{vj}^{vj} = 125 \text{ °C}; 10 \text{ ms}$		6		1250		А	
i ² t T _{vj} = 25 °C; 8,3		10 ms		11000)	A²s	
	T _{vj} = 125 °C; 8,3 10 ms			8000		A²s	
V _T	T _{vi} = 25 °C; I _T = 20	0 A	max. 1,65		V		
V _{T(TO)}	T _{vj} = 125 °C				max. 0,9		
r _T	T _{vj} = 125 °C			max. 3,5		mΩ	
I _{DD} ; I _{RD}	$T_{vj} = 125 \text{ °C}; V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$			max. 15		mA	
t _{gd}	T _{vj} = 25 °C; I _G = 1 A; di _G /dt = 1 A/μs			1		μs	
t _{gr}	V _D = 0,67 * V _{DRM}				2		
(di/dt) _{cr}	T _{vj} = 125 °C			max. 150		A/µs	
(dv/dt) _{cr}	$T_{vj} = 125 \text{ °C}$			max. 1000		V/µs	
t _q	$T_{vj} = 125 ^{\circ}C$,			80		μs	
I _H	$T_{vj} = 25 \text{ °C}; \text{ typ. } / \text{max.}$			150 / 250		mA	
IL	T_{vj} = 25 °C; R_{G} = 33 Ω ; typ. / max.			300 / 600		mA	
V _{GT}	$T_{vj} = 25 ^{\circ}C; d.c.$			min. 3		V	
I _{GT}	$T_{vj} = 25 \text{ °C; d.c.}$			min. 150		mA	
V _{GD}	T _{vj} = 125 °C; d.c.			max. 0,25		V mA	
I _{GD}	T _{vj} = 125 °C; d.c.				max. 6		
R _{th(j-c)}		ont.; per thyristor / per module			0,57 / 0,29		
R _{th(j-c)}		in. 180; per thyristor / per module		0,6 / 0,3		K/W K/W	
R _{th(j-c)}		ec. 120; per thyristor / per module er thyristor / per module			0,64 / 0,32		
R _{th(c-s)}				0,2 / 0,1 - 40 + 125		к/W °С	
T _{vj} T _{stg}				- 40 +		°C	
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.			3600 / 3000		V~	
M _s	to heatsink		$5 \pm 15 \%^{1)}$		Nm		
M _t	5			3 ± 15 %		Nm	
a				5 * 9,8		m/s²	
m	approx.			95		g	
Case	SKKT			A 46			
	SKKTB			A 48			
	SKKH			A 47			

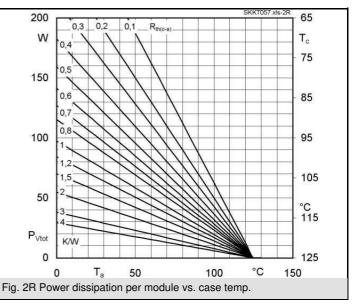


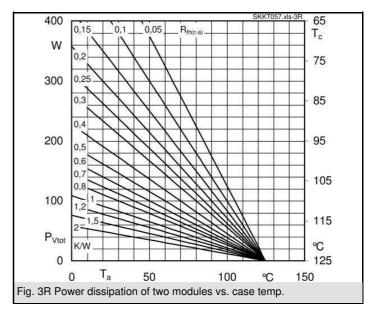






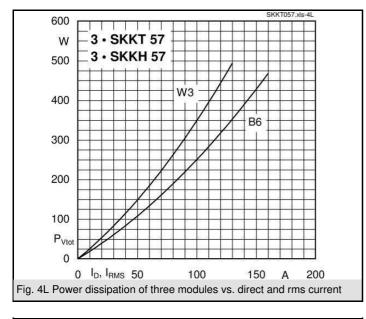


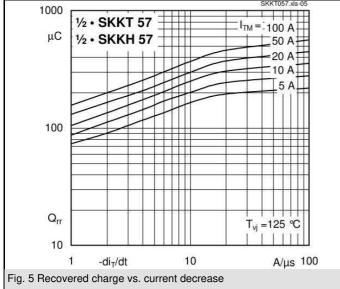


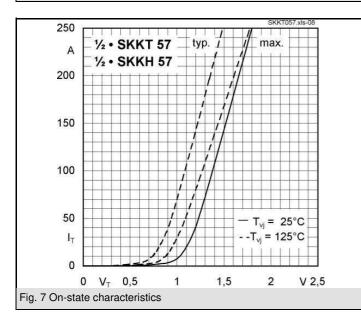


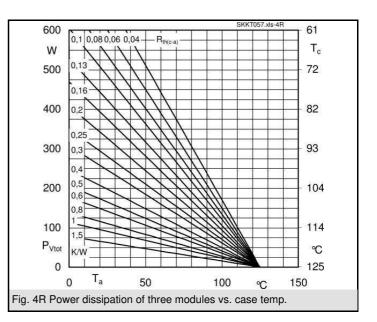
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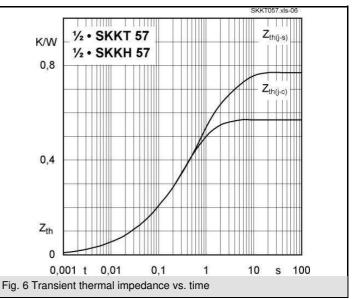
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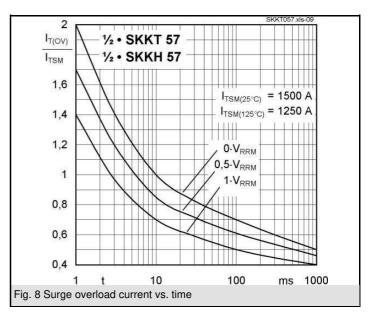


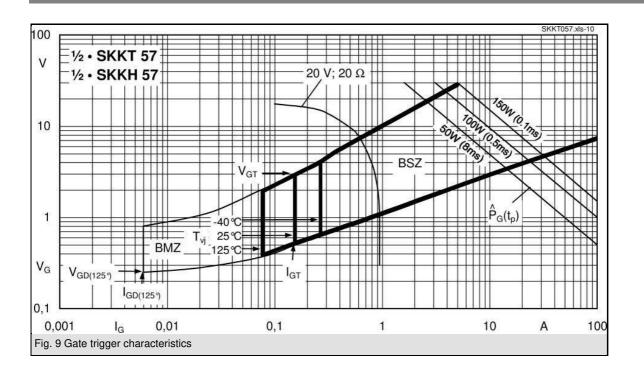


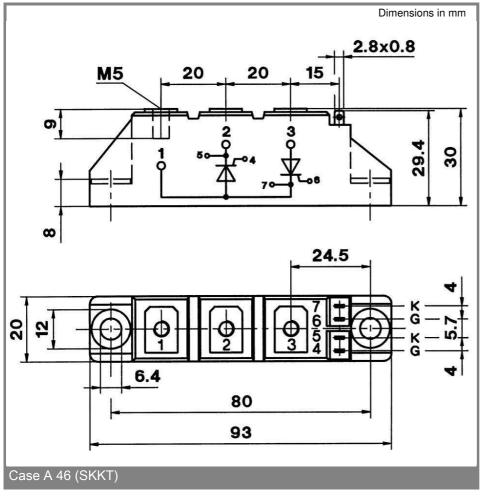


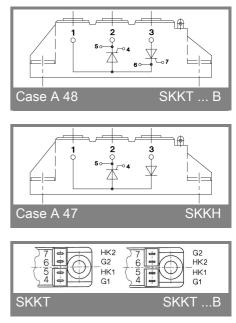












* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our staff.